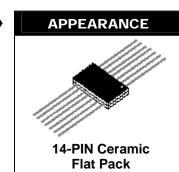


5774A

Isolated Diode Array with HiRel MQ, MX, MV, and SP Screening Options

## DESCRIPTION

These low capacitance diode arrays are multiple, discrete, isolated junctions fabricated by a planar process and mounted in a 14-PIN package for use as steering diodes protecting up to eight I/O ports from ESD, EFT, or surge by directing them to the positive side of the power supply line and to ground (see figure 1). An external TVS diode may be added between the positive supply line and ground to prevent overvoltage on the supply rail. They may also be used in fast switching core-driver applications. This includes computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, etc., as well as decoding or encoding applications. These arrays offer many advantages of integrated circuits such as high-density packaging and improved reliability. This is a result of fewer pick and place operations, smaller footprint, smaller weight, and elimination of various discrete packages that may not be as user friendly in PC board mounting.



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**IMPORTANT:** For the most current data, consult *MICROSEMI's* website: <u>http://www.microsemi.com</u>

FEATORES		<b>APPLICATIONS / BENEFITS</b>
Hermetic Ceramic Package Isolated Diodes To Eliminate Cross-Talk Voltages High Breakdown Voltage V <sub>BR</sub> > 60 V at 10 $\mu$ A Low Leakage I <sub>R</sub> < 100nA at 40 V Low Capacitance C < 8.0 pF Options for screening in accordance with MIL-PRF- 19500/474 for JAN, JANTX, JANTXV, and JANS are available by adding MQ, MX, MV, or SP prefixes respectively to part numbers. For example, designate MX5774A for a JANTX screen.		<ul> <li>High Frequency Data Lines</li> <li>RS-232 &amp; RS-422 Interface Networks</li> <li>Ethernet: 10 Base T</li> <li>Computer I/O Ports</li> <li>LAN</li> <li>Switching Core Drivers</li> <li>IEC 61000-4 Compatible (see circuit in figure 1) 61000-4-2 ESD: Air 15 kV, contact 8 kW 61000-4-4 (EFT): 40 A – 5/50 ns 61000-4-5 (surge): 12 A 8/20 μs</li> </ul>
MAXIMUM RATINGS		MECHANICAL AND PACKAGING
Reverse Breakdown Voltage of 60 Vdc (Note 1 & 2) Continuous Forward Current of 300 mA dc (Note 1 & 3) Peak Surge Current (tp=1/120 s) of 500 mA dc (Note 1) 400 mW Power Dissipation per Junction @ 25°C 500 mW Power Dissipation per Package @ 25°C (Note 4) Operating Junction Temperature range –65 to +150°C Storage Temperature range of –65 to +150°C <b>NOTE 1:</b> Each Diode		<ul> <li>14-PIN Ceramic Flat Pack</li> <li>Weight 0.29 grams (approximate)</li> <li>Marking: Logo, part number, date code and dot identifying pin #1</li> <li>Carrier Tubes; 19 pcs (standard)</li> </ul>
	Isolated Diodes To Eliminate Cross-Talk Voltages High Breakdown Voltage $V_{BR} > 60 V$ at 10 $\mu$ A Low Leakage $I_R < 100$ nA at 40 V Low Capacitance C < 8.0 pF Options for screening in accordance with MIL-PRF- 19500/474 for JAN, JANTX, JANTXV, and JANS are available by adding MQ, MX, MV, or SP prefixes respectively to part numbers. For example, designate MX5774A for a JANTX screen. <b>MAXIMUM RATINGS</b> Reverse Breakdown Voltage of 60 Vdc (Note 1 & 2) Continuous Forward Current of 300 mA dc (Note 1 & 3) Peak Surge Current (tp=1/120 s) of 500 mA dc (Note 1) 400 mW Power Dissipation per Junction @ 25°C 500 mW Power Dissipation per Package @ 25°C (Note 4) Operating Junction Temperature range –65 to +150°C	Hermetic Ceramic Package Isolated Diodes To Eliminate Cross-Talk Voltages High Breakdown Voltage $V_{BR} > 60$ V at 10 $\mu$ A Low Leakage $I_R < 100$ nA at 40 V Low Capacitance C < 8.0 pF Options for screening in accordance with MIL-PRF- 19500/474 for JAN, JANTX, JANTXV, and JANS are available by adding MQ, MX, MV, or SP prefixes respectively to part numbers. For example, designate MX5774A for a JANTX screen. <b>MAXIMUM RATINGS</b> Reverse Breakdown Voltage of 60 Vdc (Note 1 & 2) Continuous Forward Current of 300 mA dc (Note 1 & 3) Peak Surge Current (tp=1/120 s) of 500 mA dc (Note 1) 400 mW Power Dissipation per Junction @ 25°C 500 mW Power Dissipation per Package @ 25°C (Note 4) Operating Junction Temperature range –65 to +150°C Storage Temperature range of –65 to +150°C NOTE 1: Each Diode

- **NOTE 2:** Pulsed:  $P_W = 100 \text{ ms max.}$ ; duty cycle  $\leq 20\%$
- **NOTE 3:** Derate at 2.4 mA/°C above +25°C
- NOTE 4: Derate at 4.0 mW/ $^{\circ}$ C above +25 $^{\circ}$ C

MAXIMUM REVERSE MAXIMUM MAXIMUM MAXIMUM MAXIMUM **RECOVERY TIME** FORWARD FORWARD CAPACITANCE REVERSE **RECOVERY TIME** trr VOLTAGE CURRENT (PIN TO PIN)  $I_{\rm F} = I_{\rm R} = 200 \, \rm mA$ V<sub>F1</sub>  $\mathbf{C}_{t}$ i<sub>rr</sub> = 20 mA t<sub>fr</sub> I<sub>F</sub> = 100 mA  $V_R = 0 V$ I<sub>R1</sub> I<sub>F</sub> = 500 mA R<sub>L</sub> = 100 ohms (Note 1)  $V_R = 40 V$ F = 1 MHz PART NUMBER рF Vdc μAdc ns ns 8.0 40 20 5774A 1 0.1

**NOTE 1:** Pulsed:  $P_W = 300 \ \mu s \ +/- 50 \ \mu s$ , duty cycle  $\leq 2\%$ , 90  $\mu s$  after leading edge.



Isolated Diode Array with HiRel MQ, MX, MV, and SP Screening Options

Symbol	DEFINITION			
V <sub>BR</sub>	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified curren			
V <sub>F</sub>	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified			
I <sub>R</sub>		rent: The maximum leakage current that will flow at the specified volt		
Ct		citance of the TVS as defined @ 0 volts at a frequency of 1 MHz and		
c	CHEMATIC	PACKAGE DIMENSIONS		
		LO 1 14 2 13 3 12 4 11 5 10 6 9 7 8		
Supply	CIRCUIT v rail (+V <sub>cc</sub> )			
Supply	CIRCUIT	$BW_2 \rightarrow BW_1 \rightarrow BW_2$		
Supply	CIRCUIT	$BW_2 \rightarrow BW_1 \rightarrow BW_2$ $W_1 \rightarrow W_2$		
Supply	CIRCUIT	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		
	CIRCUIT v rail (+V <sub>CC</sub> )	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		
	CIRCUIT	Symbol         Inches         Millimeters           BL         .390         9.91           BW         .235         .260         5.97         6.60           CH         .045         .095         1.14         2.41		
	CIRCUIT v rail (+V <sub>CC</sub> )	Symbol         Inches         Millimeters           Min         Max         Min         Max           BL         .390         9.91           BW         .235         .260         5.97         6.60           CH         .045         .095         1.14         2.41           LL         .250         .370         6.35         9.40		
	CIRCUIT v rail (+V <sub>CC</sub> )	Symbol         Inches         Millimeters           BH2         BH2         BH2         BH2           BL         .390         9.91           BW         .235         .260         5.97         6.60           CH         .045         .095         1.14         2.41           LL         .250         .370         6.35         9.40           LO         .005         0.13         0.13         0.13		
/O Port —	CIRCUIT $\gamma$ rail (+V <sub>CC</sub> )	$\begin{array}{c c c c c c c c c c c c c c c c c c c $		
/O Port —	CIRCUIT v rail (+V <sub>CC</sub> )	Symbol         Inches         Millimeters           BH2         BH2         BH2         BH2           BL         .390         9.91           BW         .235         .260         5.97         6.60           CH         .045         .095         1.14         2.41           LL         .250         .370         6.35         9.40           LO         .005         0.13         1.14           LS         .050 BSC         1.27 BSC         1.27 BSC		
/O Port — GNI	CIRCUIT v rail (+V <sub>CC</sub> ) $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $		
I/O Port — GNI	CIRCUIT $\gamma$ rail (+V <sub>CC</sub> )	Symbol         Inches         Millimeters           BH2         BH2         BH2         BH2           BL         .390         9.91           BW         .235         .260         5.97         6.60           CH         .045         .095         1.14         2.41           LL         .250         .370         6.35         9.40           LO         .005         0.13         1.14           LS         .050 BSC         1.27 BSC         1.27 BSC           LT         .003         .006         0.08         0.15		

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